

3GPP LTE FDD BTS Measurement

MS2690A/MS2691A/MS2692A Signal Analyzer MG3700A Vector Signal Generator

MS269xA Signal Analyzer MG3700A Vector Signal Generator

3GPP LTE FDD BTS Measurement (TS36.141 v8.2.0)





July 2009 Anritsu Corporation



				MG3	700A	
	3GPP TS 36.141		MS269xA (SPA)	Memory A Wanted wave Memory B Interferen ce wave		CW SG
	6.2	Base station output power	OK			
	6.3.1	RE Power control dynamic range		Same as	item 6.5.2	
	6.3.2	Total power dynamic range	OK			
	6.4	Transmit ON/OFF power		for LTI	E(TDD)	
_	6.5.1	Frequency error	OK			
ite	6.5.2	Error Vector Magnitude	OK			
Transmitter	6.5.3	Time alignment between transmitter branches	OK			
ľa	6.5.4	DL RS power	OK			
-	6.6.1	Occupied bandwidth	OK			
	6.6.2	Adjacent Channel Leakage power Ratio (ACLR)	OK			
	6.6.3	Operating band unwanted emissions	OK			
	6.6.4	Transmitter spurious emissions	OK			
	6.7	Transmitter intermodulation	OK	E-TM1.1		
	7.2	Reference sensitivity level		OK		
	7.3	Dynamic range		OK	AWGN	
	7.4	In-channel selectivity		OK	xxRBs	
ē	7.5	Adjacent Channel Selectivity (ACS)		OK	E-UTRA	
Receiver	7.5	Narrow-band blocking		OK	1RB	
ec	7.6	Blocking		OK	E-UTRA	
<u>~</u>	7.0	Blooking		OK		OK
	7.7	Receiver spurious emissions	OK			
	7.8	Receiver intermodulation		OK	E-UTRA	OK
	, .0	Receiver intermodulation (Narrow)		OK	1RB	OK

Recommended Configuration

MS269xA Signal Analyzer
MX269020A LTE Downlink Meas. Software
MS269xA-020 Vector Signal Generator
MX269908A LTE IQproducer



MG3700A Vector Signal Generator MX370108A LTE IQproducer MX370104A Multi-Carrier IQproducer



Usually a modulated signal source is needed (item 6.7), but another signal generator is not required with the MS269xA because it has build-in signal generator option (MS269xA-020).

With the MG3700A, both the "wanted" signal and "interference signal" can be generated at one port using two different arbitrary waveform memories.



Agenda

- 1. Test Model
- 2. Transmitter Characteristics
- 3. Receiver Characteristics

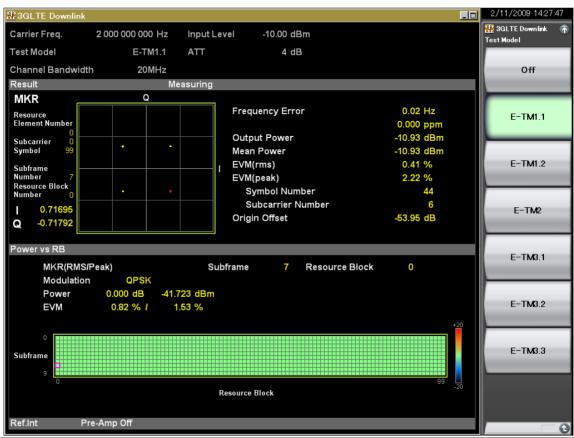


Test Model for Transmitter Characteristics

	Application	Modulation Scheme	Power Variation (at 20 MHz Bandwidth)
	Application BS Output Power	Scheme	(at 20 MHZ Baridwidth)
	Unwanted emissions		
	- Occupied bandwidth		
	- ACLR		
E-TM1.1	- Operating band unwanted emissions	QPSK	None
	- Transmitter spurious emissions		
	Transmitter intermodulation		
	RS Absolute accuracy		
E TM4 0	Unwanted emissions	ODOK	40%: +3 dB
E-TM1.2	- ACLR	QPSK	60%: -4.73 dB
	- Operating band unwanted emissions		
	Total power dynamic range (lower OFDM symbol power limit at min. power),	64QAM: 1%	64QAM: 0 dB
E-TM2	- EVM of single 64QAM PRB allocation (at min. power)	OFF: 99%	OFF: -inf
	- Frequency error (at min. power)		
	Total power dynamic range (upper OFDM symbol power limit at max. power with		
	all 64QAM PRBs allocated)		
E-TM3.1	Transmitted signal quality	64QAM	None
	- Frequency error		
	- EVM for 64QAM modulation (at max. power)		
	Transmitted signal quality	16QAM: 60%	16QAM: -3 dB
E-TM3.2	- Frequency error	QPSK: 40%	QPSK: +2.426 dB
	- EVM for 16QAM modulation	Q1 51X. 4076	Q1 311. +2.420 db
	Transmitted signal quality	16QAM: 50%	QPSK: -6 dB
E-TM3.3	- Frequency error	QPSK: 50%	16QAM: +2.427 dB
	- EVM for QPSK modulation		10QAIVI. +2.421 UD

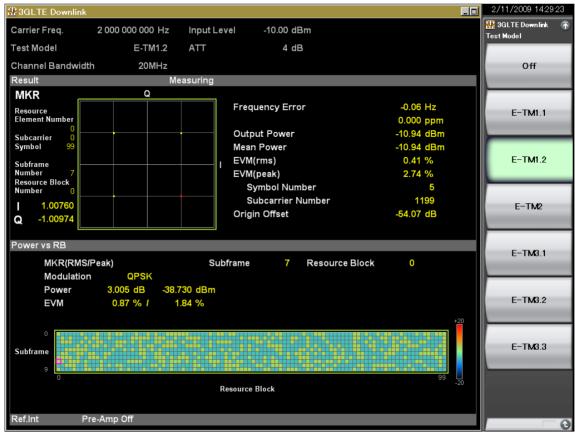


E-TM1.1



		Modulation	Power Variation
	Application Application	Scheme	(at 20 MHz Bandwidth)
	BS Output Power		
	Unwanted emissions		
	- Occupied bandwidth		
E-TM1.1	- ACLR	ODCK	None
E-1 W11.1	- Operating band unwanted emissions	QPSK	none
	- Transmitter spurious emissions		
	Transmitter intermodulation		
	RS Absolute accuracy		

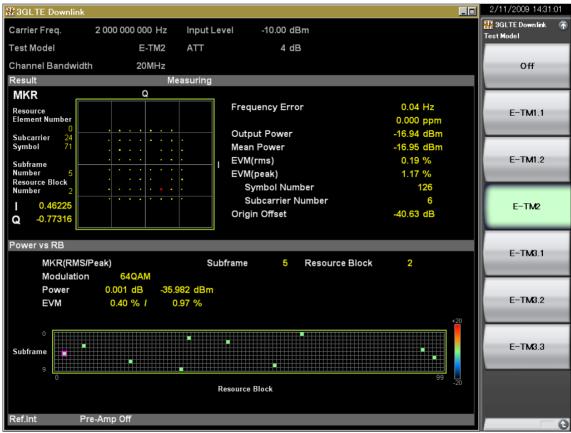
E-TM1.2



	Application		Power Variation (at 20 MHz Bandwidth)
E-TM1.2	Unwanted emissions - ACLR - Operating band unwanted emissions	QPSK	40%: +3 dB 60%: -4.73 dB



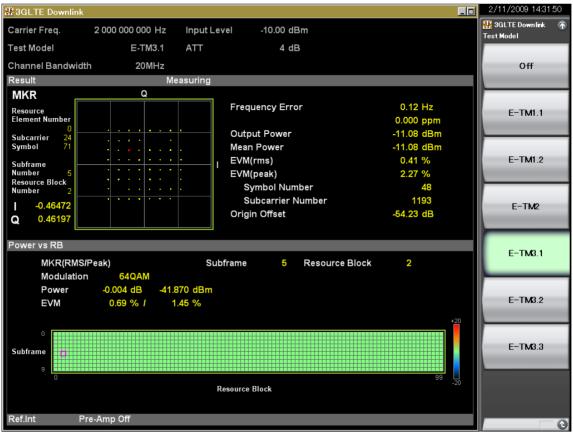
E-TM2



		Modulation	Power Variation
	Application	Scheme	(at 20 MHz Bandwidth)
E-TM	Total power dynamic range (lower OFDM symbol power limit at min. power), - EVM of single 64QAM PRB allocation (at min. power) - Frequency error (at min. power)	64QAM: 1% OFF: 99%	64QAM: 0 dB OFF: -inf

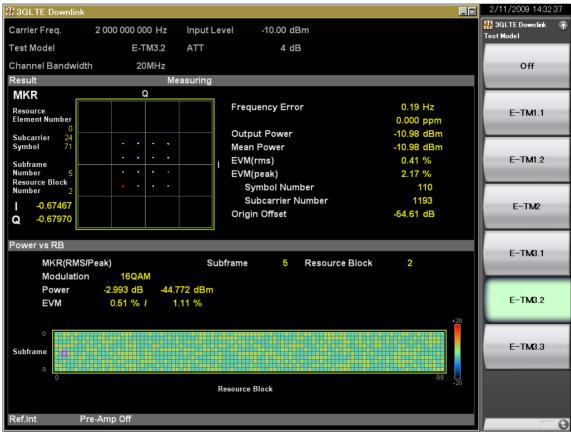


E-TM3.1



		Modulation	Power Variation
	Application	Scheme	(at 20 MHz Bandwidth)
E-TM3.1	Total power dynamic range (upper OFDM symbol power limit at max. power with all 64QAM PRBs allocated) Transmitted signal quality - Frequency error - EVM for 64QAM modulation (at max. power)	64QAM	None

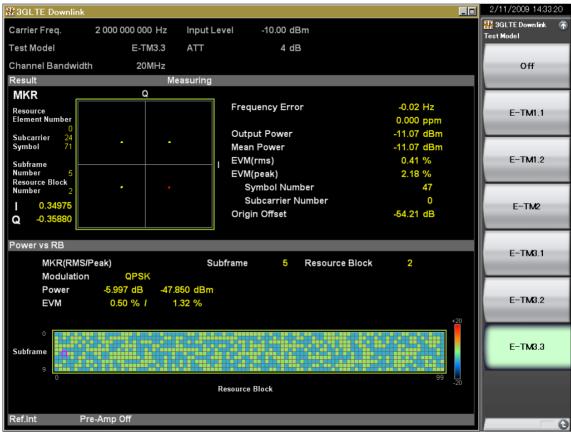
E-TM3.2



	Application		Power Variation (at 20 MHz Bandwidth)
E-TM3.2	Transmitted signal quality - Frequency error - EVM for 16QAM modulation	16QAM: 60% QPSK: 40%	16QAM: -3 dB QPSK: +2.426 dB



E-TM3.3



		Modulation	Power Variation
	Application	Scheme	(at 20 MHz Bandwidth)
E-TM3.3	Transmitted signal quality	16QAM: 50%	QPSK: -6 dB
	3.3 - Frequency error	QPSK: 50%	16QAM: +2.427 dB
	- EVM for QPSK modulation		10QAIVI. +2.427 UB



Transmitter Characteristics Measurements

TS36.141	Meas. Items	Test Model	Note
	Transmitter Characte	eristics	
6.2	Base station output power	E-TM1.1	
6.3.1	RE Power control dynamic range	-	Meaure at 6.5.2
6.3.2	Total power dynamic range	E-TM2 E-TM3.1	
6.4	Transmit ON/OFF power	-	for LTE(TDD)
6.5.1	Frequency error	E-TM2 E-TM3.1	
6.5.2	Error vector magnitude	E-TM3.2 E-TM3.3	
6.5.3	Time alignment between transmitter branches		Needed reference trigger
6.5.4	DL RS power	E-TM1.1	
6.6.1	Occupied bandwidth		
6.6.2	Adjacent channel leakage power ratio (ACLR)	E-TM1.1	
6.6.3	Operating band unwanted emissions	E-TM1.2	
6.6.4	Transmitter spurious emissions		
6.7	Transmitter intermodulation	E-TM1.1	Needed modulated signal source



Frequency Error

6.2 Base Station Output Power

Mean power measurement

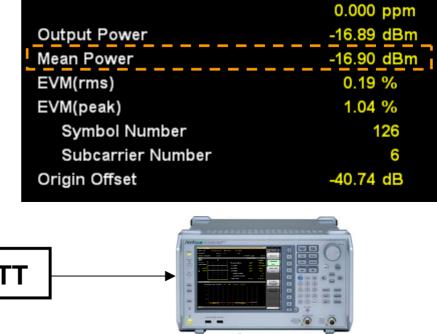
Procedure

- (1) Output E-TM1.1 from BTS
- (2) Measure mean power

Specification

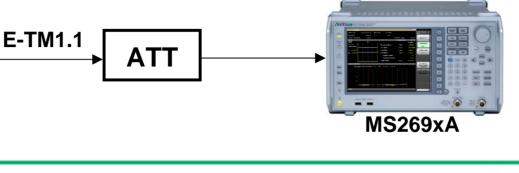
- (1) \pm 2.7 dB (normal conditions)
- (2) ± 3.2 dB (extreme conditions)

BTS



3GLTF Downlink Measurement Software

[Trace] > [F1: Trace Mode] > [F1] to [F5]





0.05 Hz

Control

6.3.2 Total Power Dynamic Range

Measure difference between max. value and min. value for OFDM symbol power.

Procedure

- (1) Output E-TM3.1 from BTS (Upper)
- (2) Measure averaged OFDM symbol power
- (3) Output E-TM2 from BTS (Lower)
- (4) Measure averaged OFDM symbol power
- (5) Calculate difference between TM3.1 and TM2

Specification

E-UTRA	Total power dynamic
channel bandwidth (MHz)	range (dB)
1.4	7.7 – [TT]
3	11.7 – [TT]
5	13.9 – [TT]
10	16.9 – [TT]
15	18.7 – [TT]
20	20 – [TT]

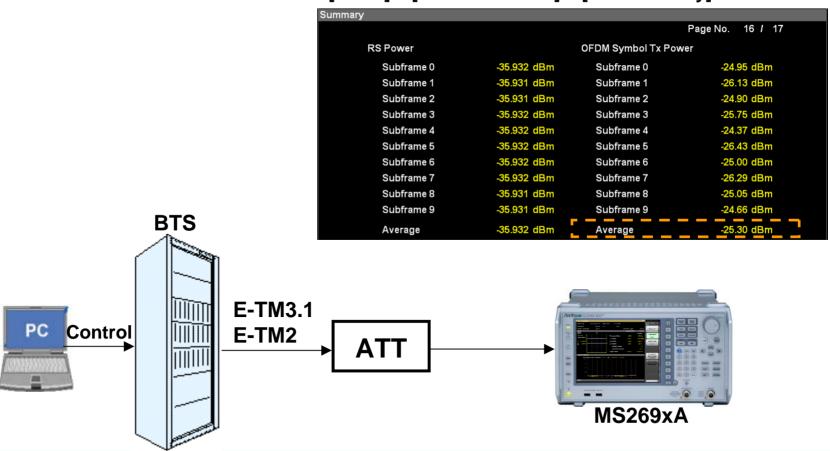
(3GPP TS36.141)



6.3.2 Total Power Dynamic Range

3GLTE Downlink Measurement Software

[Trace] > [F1: Trace Mode] > [F6: Summary]





6.5.1 Frequency Error

6.5.2 Error Vector Magnitude

Procedure

- (1) Output E-TM2/3.1/3.2/3.3 from BTS sequentially
- (2) Measure Frequency error and EVM each test model

Specification for Frequency Error

± 0.05 ppm

Specification for Error Vector Magnitude

Modulation scheme for PDSCH	Required EVM [%]
QPSK	17.5 + [TT] %
16QAM	12.5 + [TT] %
64QAM	8 + [TT] %

(3GPP TS36.141)

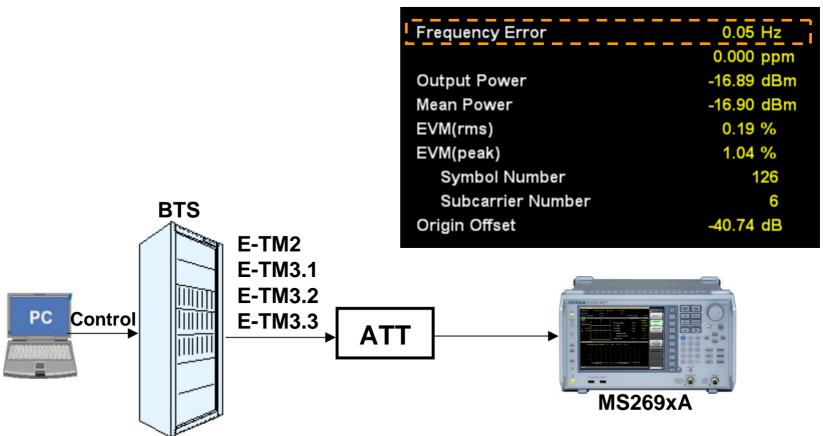


6.5.1 Frequency Error

6.5.2 Error Vector Magnitude

3GLTE Downlink Measurement Software

[Trace] > [F1: Trace Mode] > [F1] to [F5]



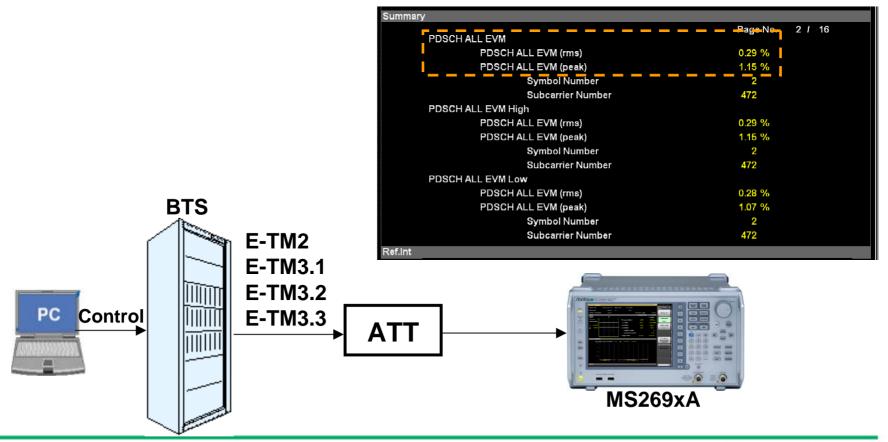


6.5.1 Frequency Error

6.5.2 Error Vector Magnitude

3GLTE Downlink Measurement Software

[Trace] > [F1: Trace Mode] > [F1] to [F5]





6.5.3 Time Alignment between Transmitter Branches

Procedure

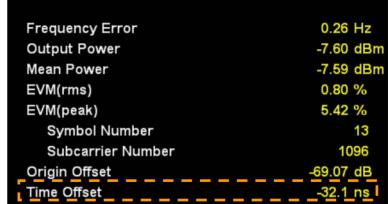
- (1) Output reference signal (trigger) from BTS to MS269xA
- (2) Output TM1 from BTS antenna 1
- (3) Measure time offset
- (4) Measure antenna 2 in same way as (2) and (3)
- (5) Calculate difference

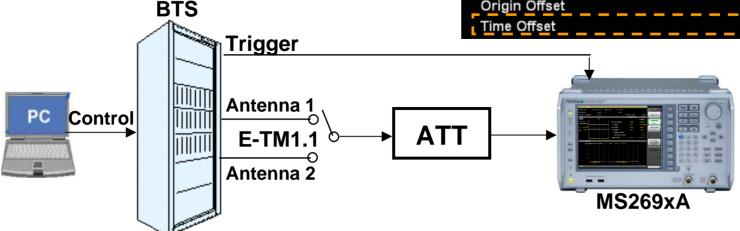
Specification

within 65 ns

3GLTE Downlink Measurement Software

[Trace] > [F1: Trace Mode] > [F1] to [F5] (Time Offset enabled when External Trigger On)







6.5.4 DL RS Power

Measure difference between setting value and actual measured value for DL RS Power

Procedure

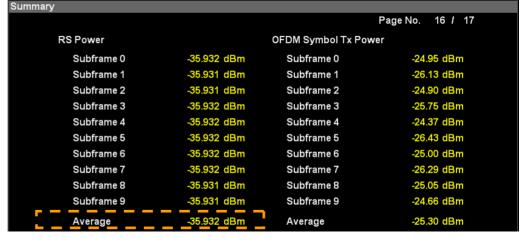
- (1) Output E-TM1.1 from BTS
- (2) Measure RS Power
- (3) Calculate actual measured value

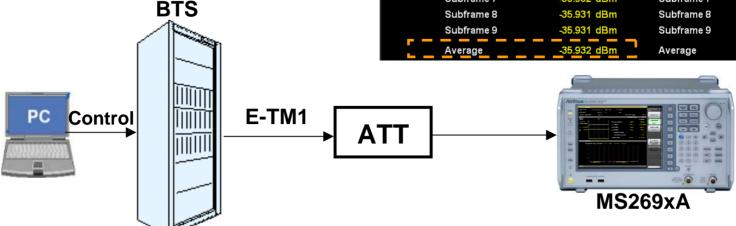
Specification

± 2.1 dB

3GLTE Downlink Measurement Software

[Trace] > [F1: Trace Mode] > [F6: Summary]







3GLTF Downlink Measurement Software

[Measure] > [F6] or [F7]

6.6.1 Occupied Bandwidth

Procedure

(1) Output E-TM1.1 from BTS

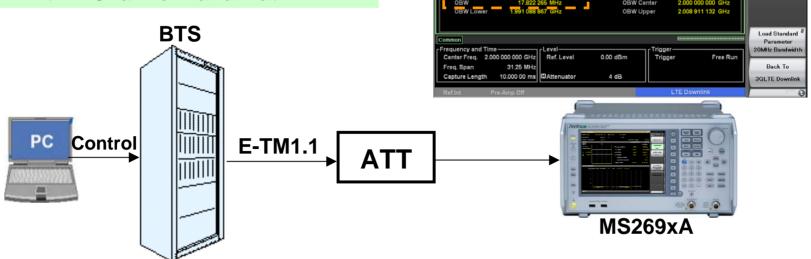
(2) Setting for spectrum analyzer

Span: 20 MHz RBW: 30 kHz Point: > 400

(3) Measure OBW (99% power)

Specification

within Channel Bandwidth





YdR Volu

6.6.2 Adjacent Channel Leakage Power Ratio

Procedure

- (1) Output E-TM1.1/1.2 from BTS sequentially
- (2) Measure ACLR each test model

Specification

E-UTRA transmitted signal channel bandwidth BW _{Channel} [MHz]	BS adjacent channel centre frequency offset below the first or above the last carrier centre frequency transmitted	Assumed adjacent channel carrier (informative)	Filter on the adjacent channel frequency and corresponding filter bandwidth	ACLR limit
1.4, 3.0, 5, 10, 15, 20	BW _{Channel}	E-UTRA of same BW	Square (BW _{Config})	44.2 dB
	2 x BW _{Channel}	E-UTRA of same BW	Square (BW _{Config})	44.2 dB
	BW _{Channel} /2 + 2.5 MHz	3.84 Mcps UTRA	RRC (3.84 Mcps)	44.2 dB
	BW _{Channel} /2 + 7.5 MHz	3.84 Mcps UTRA	RRC (3.84 Mcps)	44.2 dB

NOTE 1: BW_{Channel} and BW_{Config} are the channel bandwidth and transmission bandwidth configuration of the E-

UTRA transmitted signal on the assigned channel frequency.

NOTE 2: The RRC filter shall be equivalent to the transmit pulse shape filter defined in [15], with a chip rate as

defined in this table.

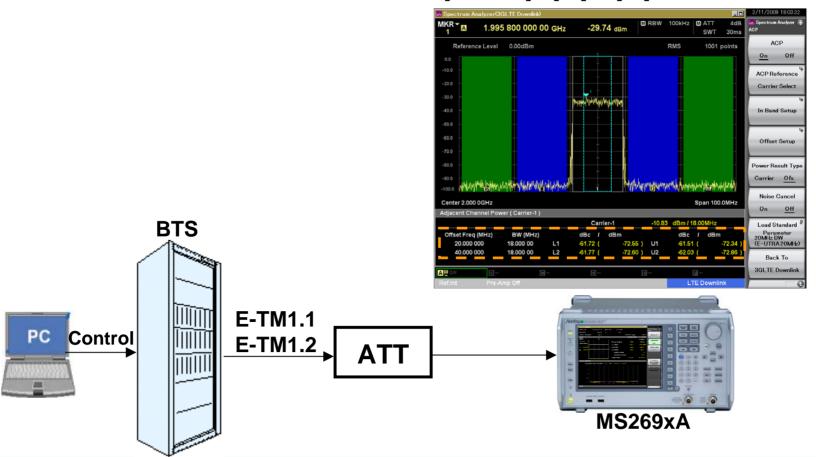
(3GPP TS36.141)



6.6.2 Adjacent Channel Leakage Power Ratio

3GLTE Downlink Measurement Software

[Measure] > [F2] or [F3]





Reference Level

Center 2 000 0GHz

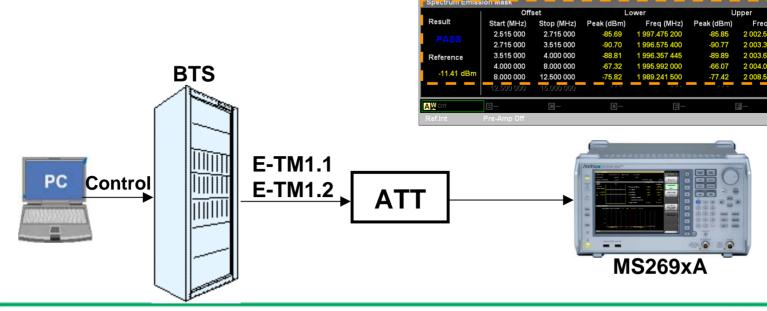
6.6.3 Operation Band Unwanted Emissions

Procedure

- (1) Output E-TM1.1/1.2 from BTS sequentially
- (2) Measure SEM for each test model

Specification

within each limit range





2 000GHz

100 OMIL-

4.100GHz

Offset Value

Step Size

Measuring...

Span 25 00MHz

6.6.4 Transmitter Spurious Emissions

Snectrum Analyzei SWT **Procedure** Reference Level Positive Emission (1) Output E-TM1.1 from BTS Segment Setup (2) Measure spurious emission Limit Cotum **Specification** Displayed Segment within each limit range Page of Summan Previous Page Limit Next Page **BTS** E-TM1.1 **BRF** Control MS269xA

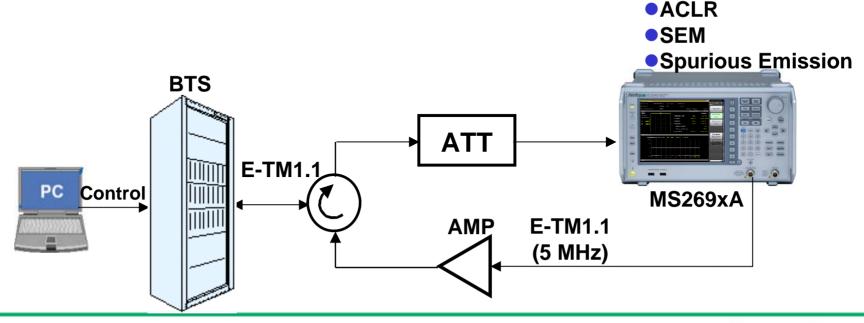


6.7 Transmitter Inter-modulation

Procedure

- (1) Output E-TM1.1 from BTS
- (2) Output interfering E-TM1.1 (5 MHz bandwidth) signal from SG with following offset sequence
 - 1. $Bw_{channel}/2 + 2.5 MHz$ 2. $Bw_{channel}/2 2.5 MHz$

 - 3. Bw_{channel} /2 + 7.5 MHz 4. Bw_{channel} /2 7.5 MHz 5. Bw_{channel} /2 + 12.5 MHz 6. Bw_{channel} /2 12.5 MHz
- (3) Measure ACLR, SEM and spurious emission in each case





Receiver Characteristics Measurements

TS36.141	Measurement items	Configuration					
Receiver Characteristics		MG3700A					
		Platform	MX370108A (opt)	MX370104A (opt)	AWGN (std)	Clipping (std)	CW SG
7.2	Reference sensitivity level	ОК					
7.3	Dynamic range	OK			OK		
7.4	In-channel selectivity					OK(*2)	
7.5	Adjacent channel selectivity (ACS) and narrow-band blocking	OK(*1)	OK	OK(*1)		OK(*2)	
7.6	Blocking (modulated interfere signal)						
7.6	Blocking (CW Interfere Signal)	OK					OK
7.7	Receiver spurious emissions	MS269xA					
7.8	Receiver intermodulation	OK(*1)	OK	OK(*1)		OK(*2)	OK

MX370108A LTE IQproducer MX370104A Multi-Carrier IQproducer

- *1: MG3700A can generate combination signal (wanted signal and modulated interference signal) using two arbitrary waveform memories. Need MX370104A Multi-Carrier IQproducer to create the interference signal.
- *2: Need narrow bandwidth modulated interference signal (1RB, 10RB etc.). After creating 1RB and 10RB, etc., pattern using LTE IQproducer, perform clip-free filtering using Clipping (standard IQproducer function).



7.2 Reference sensitivity level

Procedure

- (1) Set test signal as shown in table
- (2) Measure throughput

E-UTRA channel bandwidth [MHz]	Reference measurement channel	Reference sensitivity power level, P _{REFSENS} [dBm]
1.4 FRC A1-1 in Annex A		-106.1
3	FRC A1-2 in Annex A.1	-102.3
5	FRC A1-3 in Annex A.1	-100.8
10	FRC A1-3 in Annex A.1*	-100.8
15	FRC A1-3 in Annex A.1*	-100.8
20	FRC A1-3 in Annex A.1*	-100.8

Note*: PREFSENS is the power level of a single instance of the reference measurement channel. This requirement shall be met for each consecutive application of a single instance of FRC A1-3 mapped to disjoint frequency ranges with a width of 25 Resource Blocks each.

(3GPP TS36.141)

Specification

Throughput ≥95%



7.2 Reference Sensitivity Level

LTE IQproducer (option) Create LTE wanted signal pattern using LTE IQproducer. After transferring created pattern to MG3700A hard disk, can generate pattern from MG3700A without PC. PC **BTS Throughput Transfer Wanted Signal** Rx(1.4 to 20 MHz) PC **MG3700A**



7.3 Dynamic Range

Procedure

- (1) Set test signal as in table
- (2) Measure throughput

	Interference
Wanted signal	signal (AWGN) ▲

	· · · · · · · · · · · · · · · · · · ·				
E-UTRA channel bandwidth [MHz]	Reference measurement channel	Wanted signal mean power [dBm]	Interfering signal mean power [dBm] /channel BW	Type of interfering signal	
1.4	FRC A2-1 in Annex A.2	-76.3+[TT]	-88.7	AWGN	
3	FRC A2-2 in Annex A.2	-72.4+[TT]	-84.7	AWGN	
5	FRC A2-3 in Annex A.2	-70.2+[TT]	-82.5	AWGN	
10	FRC A2-3 in Annex A.2*	-70.2+[TT]	-79.5	AWGN	
15	FRC A2-3 in Annex A.2*	-70.2+[TT]	-77.7	AWGN	
20	FRC A2-3 in Annex A.2*	-70.2+[TT]	-76.4	AWGN	
20	FRC A2-3 in Annex A.2*	-70.2+[TT]		AWGN	

Note*: The wanted signal mean power is the power level of a single instance of the reference measurement channel. This requirement shall be met for each consecutive application of a single instance of FRC A2-3 mapped to disjoint frequency ranges with a width of 25 resource blocks each

(3GPP TS36.141)

Specification

Throughput ≥95%



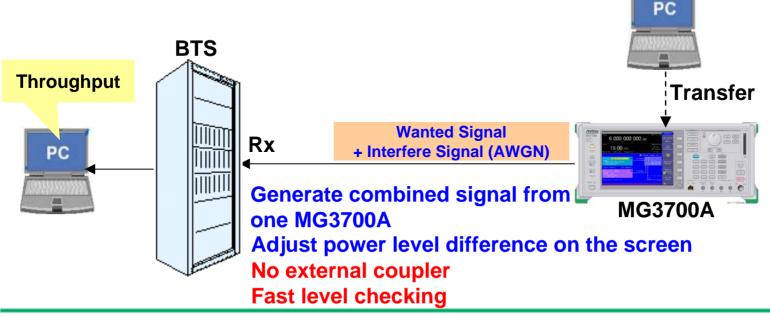
7.3 Dynamic Range

Create LTE wanted signal pattern using LTE IQproducer.

Use AWGN function as standard function. Easy to create by selecting expected signal (LTE) and selecting bandwidth scale (1/1.5/2/2.5).

LTE IQproducer (option) (standard function)

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7.4 In-channel Selectivity

Procedure

(1) Set test signal as the table below

(2) Measure the throughput

E-UTRA CH BW

Interference
Signal
(Modulated)
Signal

Wanted signal

Interference signal (16QAM)

-			
Reference measurement channel	Wanted signal mean power [dBm]	Interfering signal mean power [dBm]	Type of interfering signal
A1-4 in Annex A.1 3RBs	-106.9+[TT]	-87	1.4 MHz E-UTRA signal, 3 RBs
A1-5 in Annex A.1 9RBs	-102.1+ [TT]	-84	3 MHz E-UTRA signal, 6 RBs
A1-2 in Annex A.1 _{15RBs}	-100.0+ [TT]	-81	5 MHz E-UTRA signal, 10 RBs
A1-3 in Annex A.1 _{25RBs}	-98.5+ [TT]	-77	10 MHz E-UTRA signal, 25 RBs
A1-3 in Annex A.1* 25RBs	-98.5+ [TT]	-77	15 MHz E-UTRA signal, 25 RBs*
A1-3 in Annex A.1* 25RBs	-98.5+ [TT]	-77	20 MHz E-UTRA signal, 25 RBs*
	Measurement channel A1-4 in Annex A.1 3RBs A1-5 in Annex A.1 9RBs A1-2 in Annex A.1 15RBs A1-3 in Annex A.1 25RBs A1-3 in Annex A.1 25RBs A1-3 in Annex A.1 25RBs A1-3 in Annex A.1 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3	measurement channel mean power [dBm] A1-4 in Annex A.1 3RBs -106.9+[TT] A1-5 in Annex A.1 9RBs -102.1+[TT] A1-2 in Annex A.1 15RBs -100.0+[TT] A1-3 in Annex A.1 25RBs -98.5+[TT] A1-3 in Annex A.1 25RBs -98.5+[TT] A1-3 in Annex A.1 25RBs -98.5+[TT]	measurement channel mean power [dBm] signal mean power [dBm] A1-4 in Annex A.1 3RBs -106.9+[TT] -87 A1-5 in Annex A.1 9RBs -102.1+[TT] -84 A1-2 in Annex A.1 15RBs -100.0+[TT] -81 A1-3 in Annex A.1 25RBs -98.5+[TT] -77 A1-3 in Annex A.1 25RBs -98.5+[TT] -77 A1-3 in Annex A.1 25RBs -98.5+[TT] -77

Note*: ← Wanted and interfering signal are placed adjacently around DC

Specification

Throughput ≥95%

(3GPP TS36.141)



7.4 In-channel Selectivity

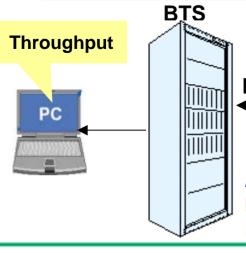
Create wanted LTE signal pattern with specified RB number using LTE IQproducer.

For interference signal, first create waveform pattern with specified RB number near center frequency using LTE IQproducer. Then drift ½ RB (90 kHz) from center frequency (symmetrical) using Multi-Carrier IQproducer. Finally, cut nearby noise with ideal filter using clipping function.

LTE IQproducer (option)

Multi-Carrier IQproducer (option) Clipping Function (standard)







Generate combined signal from one MG3700A

Adjust frequency offset and power level difference on screen No external coupler Fast level checking



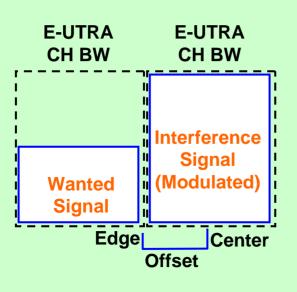
PC



7.5 Adjacent Channel Selectivity and Narrow Band Blocking

Procedure

- (1) Set test signal as in table
- (2) Measure throughput



Wanted signal

Interference signal (Modulated signal)

E-UTRA channel bandwidth [MHz]	Wanted signal mean power [dBm]	Interfering signal mean power [dBm]	Interfering signal centre frequency offset from the channel edge of the wanted signal [MHz]	Type of interfering signal
1.4	P _{REFSENS} + 11dB*	-52	0.7025	1.4MHz E-UTRA signal
3	P _{REFSENS} + 8dB*	-52	1.5075	3MHz E-UTRA signal
5	P _{REFSENS} + 6dB*	-52	2.5075	5MHz E-UTRA signal
10	P _{REFSENS} + 6dB*	-52	2.5025	5MHz E-UTRA signal
15	P _{REFSENS} + 6dB*	-52	2.5125	5MHz E-UTRA signal
20	P _{REFSENS} + 6dB*	-52	2.5025	5MHz E-UTRA signal
Note*: Prefisens depends on the channel bandwidth as specified in TS 36.104 [2] subclause 7.2.1.				

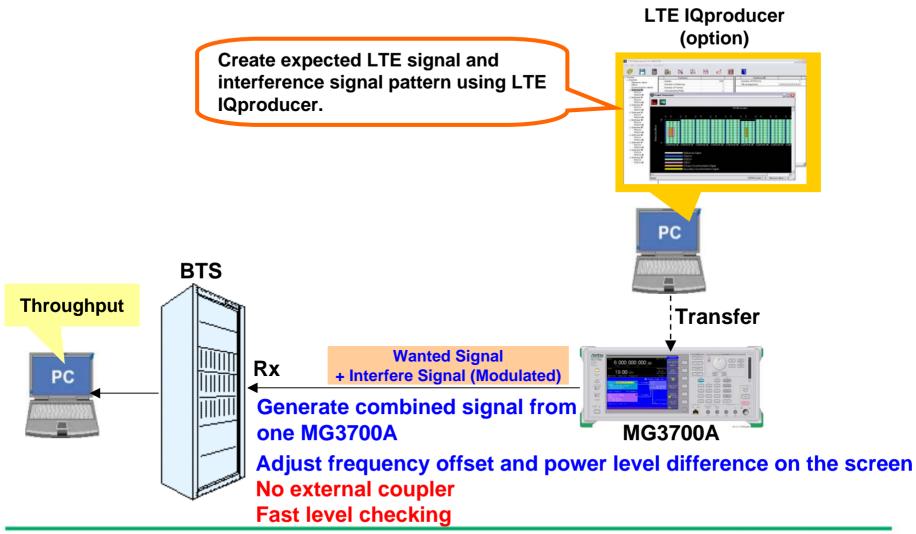
(3GPP TS36.141)

Specification

Throughput ≥95%

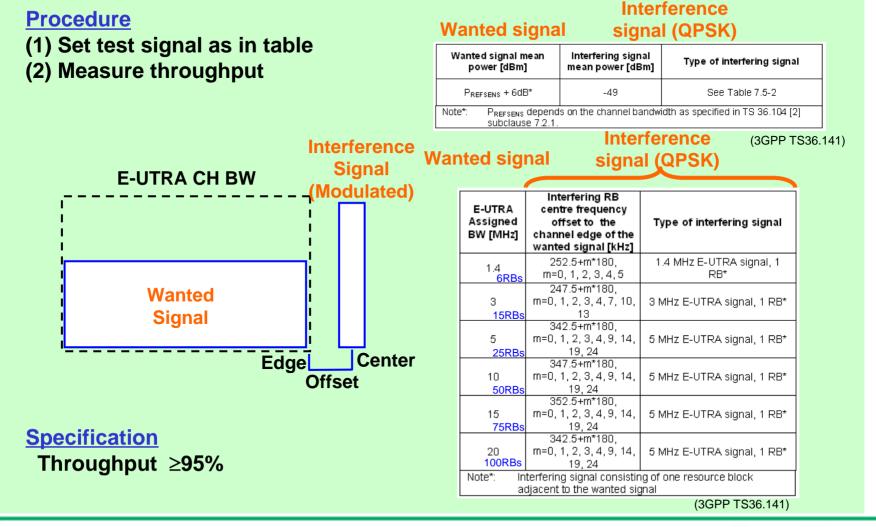


7.5 Adjacent Channel Selectivity and Narrow Band Blocking





7.5 Adjacent Channel Selectivity and Narrow Band Blocking



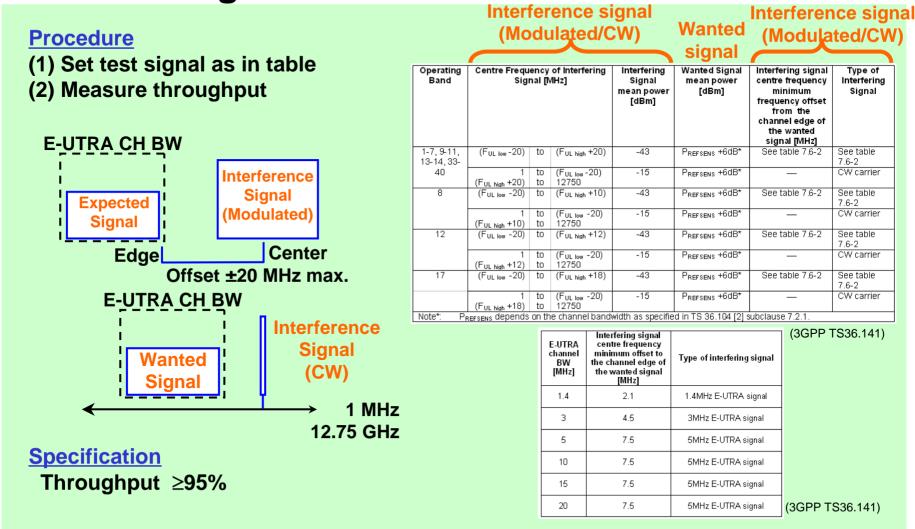


7.5 Adjacent Channel Selectivity and Narrow Band Blocking

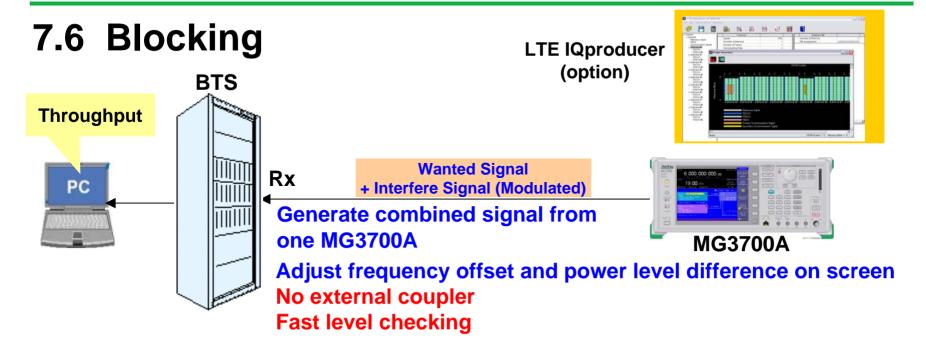
Multi-Ccarrier Clippina **Create wanted LTE signal pattern** LTE IQproducer **Function IQproducer** using LTE IQproducer. (option) (standard) (option) For interference signal, first create waveform pattern specified 1 RB number near center frequency using LTE IQproducer. Then drift ½ RB (90 kHz) from center frequency (symmetrical) with Multi-Carrier IQproducer. Finally, cut nearby noise with ideal filter using clipping PC function. **BTS Throughput Transfer Wanted Signal** Rx + Interfere Signal (1RB) PC **Generate combined signal from** one MG3700A MG3700A Adjust frequency offset and power level difference on screen No external coupler Fast level checking

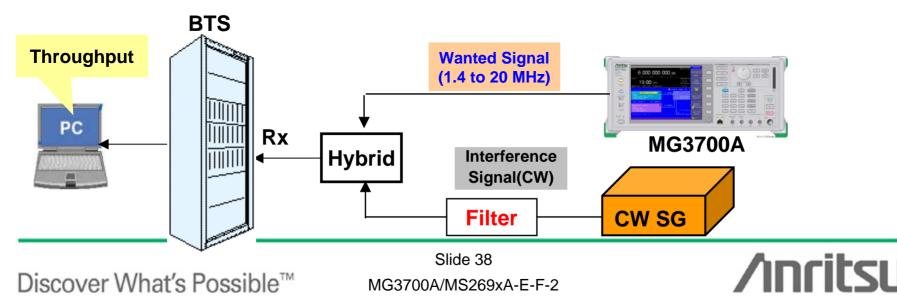


7.6 Blocking









7.7 Receiver Spurious Emissions

Procedure

- (1) Transfer E-TM1.1 with Pmax from BTS
- (2) Terminate Tx port
- (3) Measure spurious at Rx port

Frequency range	Maximum level	Measurement Bandwidth	Note
30MHz - 1 GHz	-57 dBm	100 kHz	
1 GHz - 12.75 GHz	-47 dBm	1 MHz	

NOTE:

The frequency range between 2.5 * BW_{Charmel} below the first carrier frequency and 2.5 * BW_{Charmel} above the last carrier frequency transmitted by the BS, where BW_{Charmel} is the channel bandwidth according to Table 5.6-1, may be excluded from the requirement. However, frequencies that are more than 10 MHz below the lowest frequency of the BS downlink operating band or more than 10 MHz above the highest frequency of the BS downlink operating band (see Table 5.5-1) shall not be excluded from the requirement.

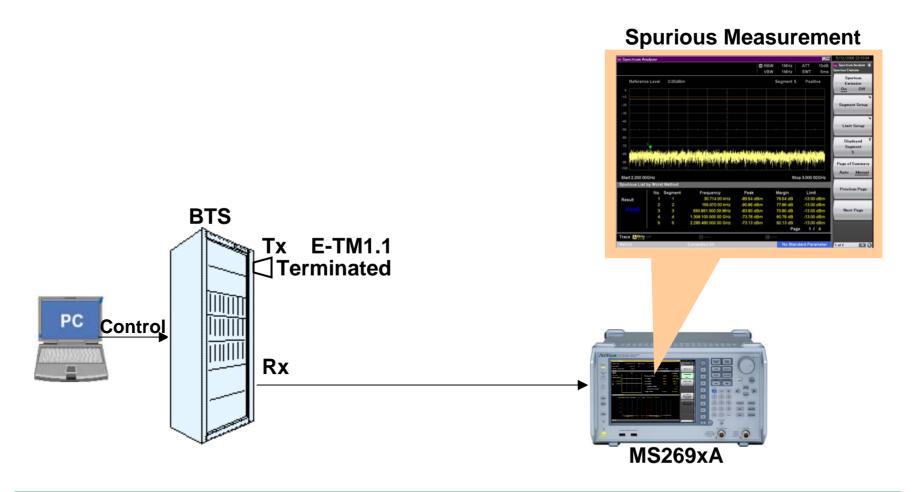
(3GPP TS36.141)

Specification

Not exceeding power level in above table



7.7 Receiver Spurious Emissions





7.8 Receiver Inter-modulation

Procedure

- (1) Set test signal as in table
- (2) Measure throughput

Specification

Throughput ≥95%

Wanted Interference signal (Modulated/CW)

Wanted signal mean power [dBm]		Interfering signal mean power [dBm]	Type of interfering signal
P _{REFSENS} + 6dB*		-52	See Table 7.8-2
Note*: P _{REFSENS} depends on the channel bandwidth as specified in TS 36.104 [2] subclause 7.2.1.			

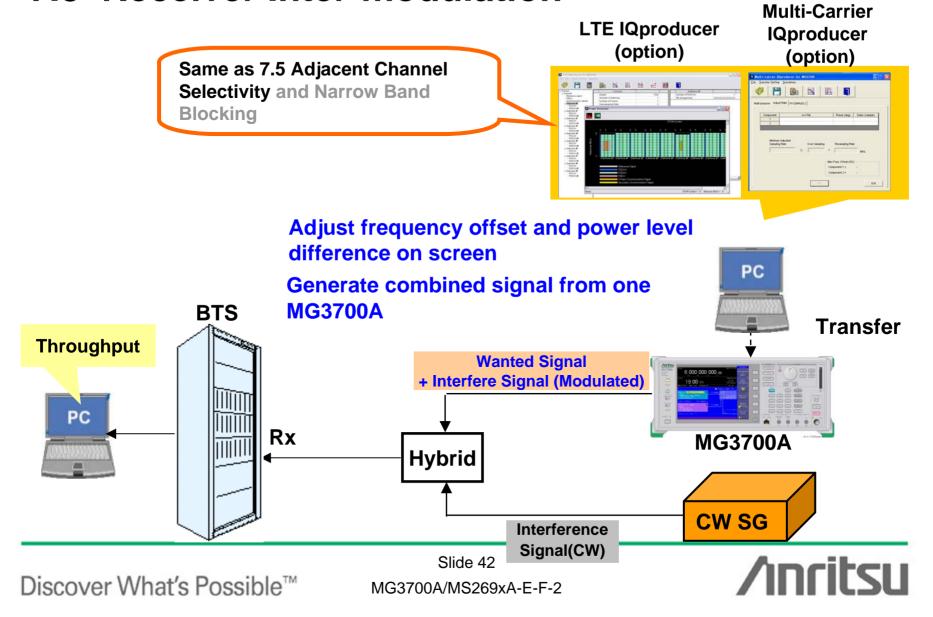
Interference signal (Modulated/CW)

(3GPP TS36.141)

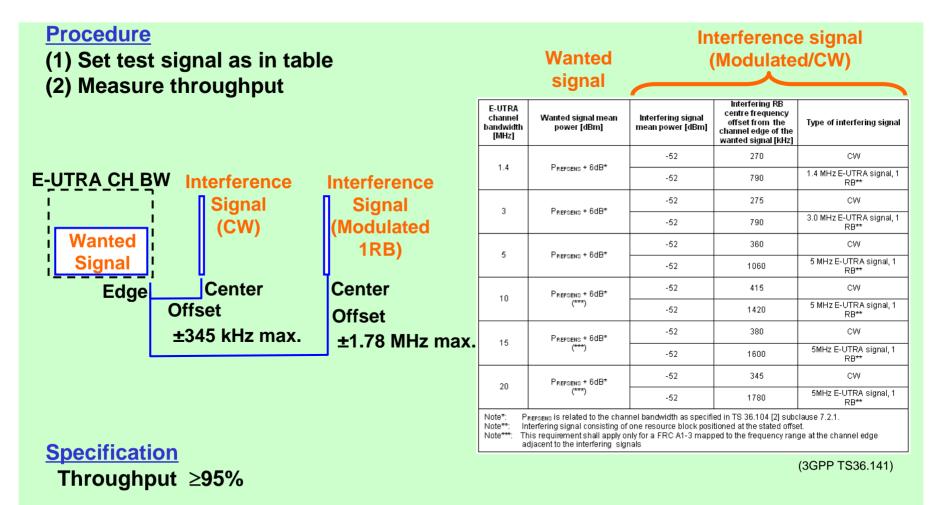
E-UTRA channel bandwidth [MHz]	Interfering signal centre frequency offset from the channel edge of the wanted signal [MHz]	Type of interfering signal
1.4	2.1	cw
1.4	4.9	1.4MHz E-UTRA signal
3	4.5	cw
,	10.5	3MHz E-UTRA signal
5	7.5	cw
5	17.5	5MHz E-UTRA signal
10	7.5	cw
'0	17.7	5MHz E-UTRA signal
15	7.5	cw
15	18	5MHz E-UTRA signal
20	7.5	cw
20	18.2	5MHz E-UTRA signal

(3GPP TS36.141)

7.8 Receiver Inter-modulation

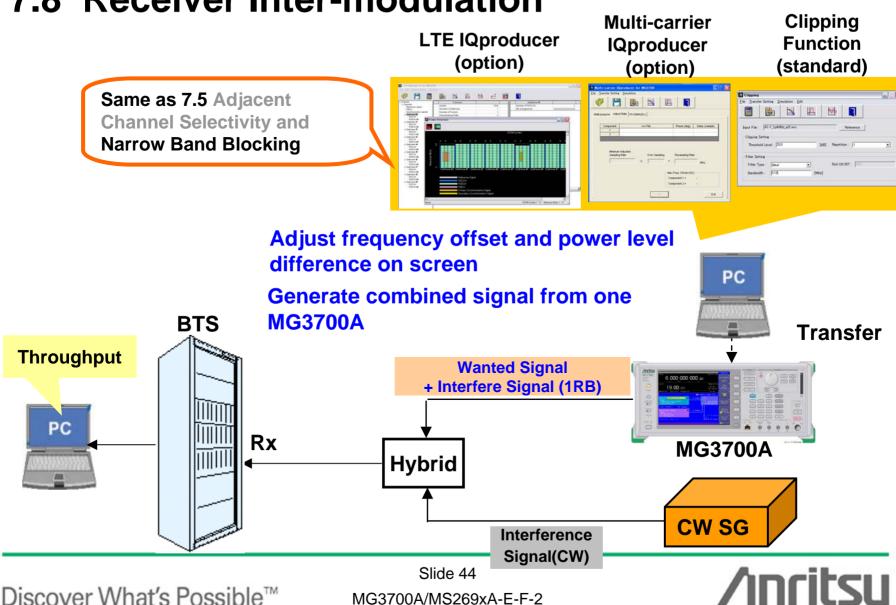


7.8 Receiver Inter-modulation (Narrowband)





7.8 Receiver Inter-modulation





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